## NSN 5961-01-339-9720

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-9720 **Inclosure Material:** Glass or ceramic **Overall Length:** Between 0.130 inches and 0.300 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.110 inches and 0.180 inches **Function For Which Designed:** Rectifier **End Application:** Radar set an/sps-40d **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, instantaneous and 500.0 working peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No